

15th Trento Workshop

on Advanced Silicon Radiation Detectors



LPNHE - FBK thin n-on-p pixels for HL-LHC upgrades and beyond

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Outline

- Tracking at HL-LHC and beyond
- Recent LPNHE planar pixel productions at FBK
- Testbeam results
- Conclusions and outlook

Challenges for the future ATLAS tracker

- Instantaneous luminosity : $L_{\text{inst}} = 5-7 \times 10^{34} \text{ cm}^{-2}\text{s}^{-1}$
 - x3-5 more than today
- Events-pile up: $\mu \approx 140 - 200 \text{ events/Bunch Crossing}$
 - x4-6 more than today

➤ **Need to increase the pixel granularity**

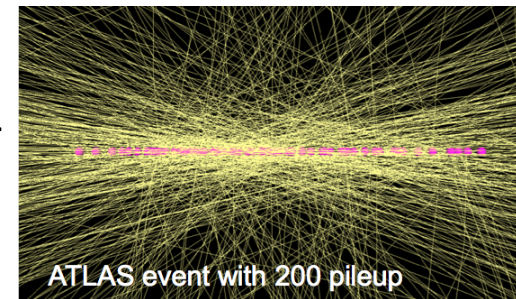
- Actual pixel size: $50 \times (250-400) \mu\text{m}^2$

- Expected fluence: $\phi = 1-2 \times 10^{16} n_{\text{eq}}/\text{cm}^2$
 - $2-3 \times 10^{15} n_{\text{eq}}/\text{cm}^2$ for planar sensors

➤ **Need radiation-hard detectors**

➤ **Goal: better performance in a harsher environment!**

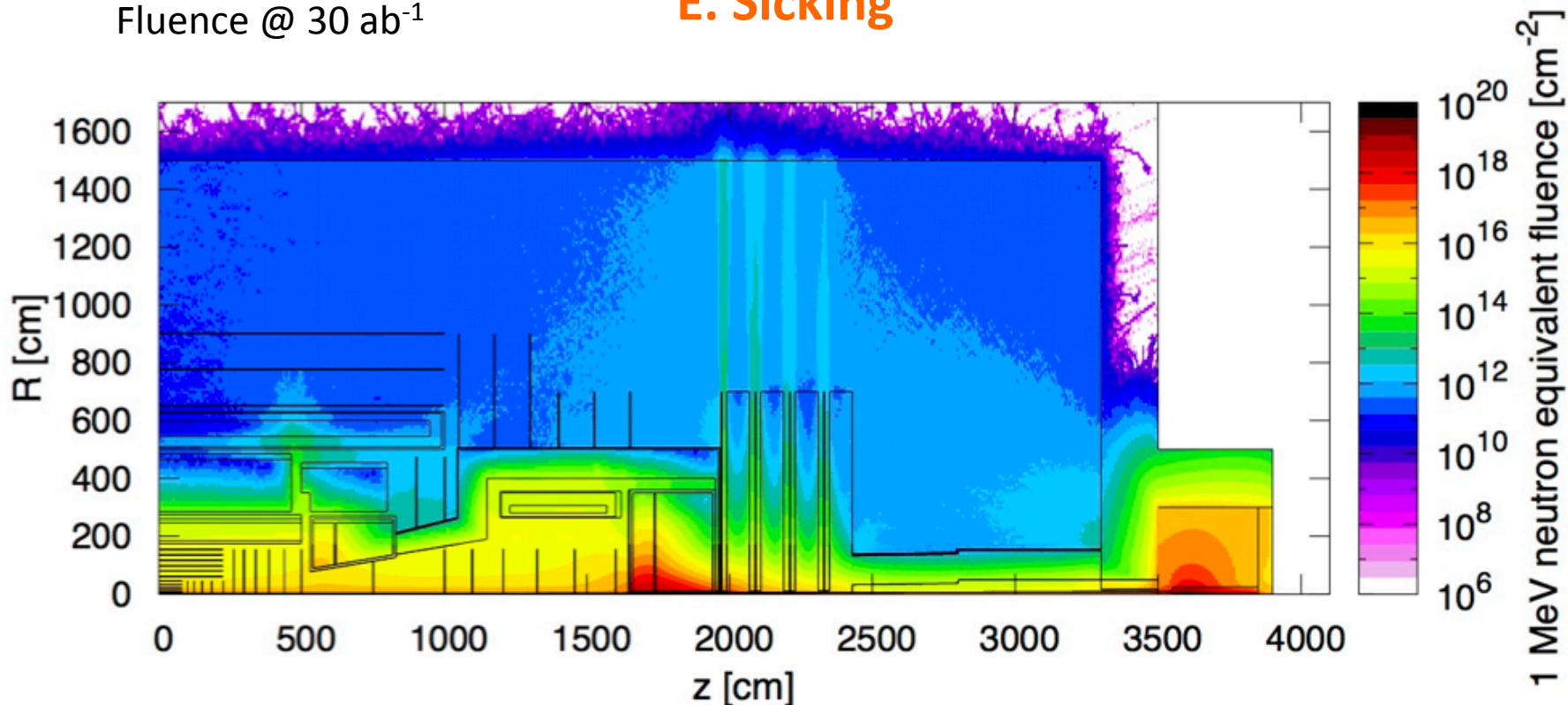
See talks by Q. Buat and J. Lange



Tracking at FCC-hh

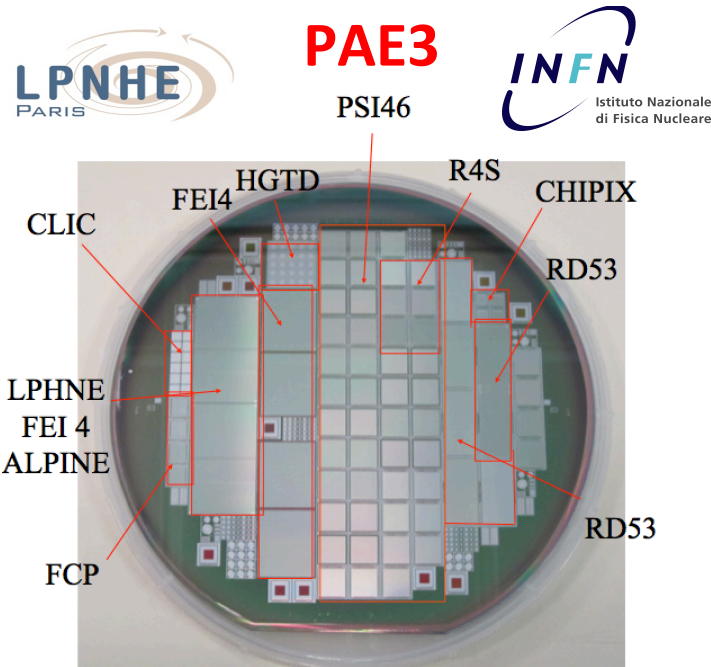
E. Sicking

Fluence @ 30 ab⁻¹



Fluence up to $5 \times 10^{17} \text{ n}_{\text{eq}}/\text{cm}^2 \Rightarrow$ **need thin detectors**
Very low material budget \Rightarrow **need thin detectors**

Recent LPNHE planar pixel productions

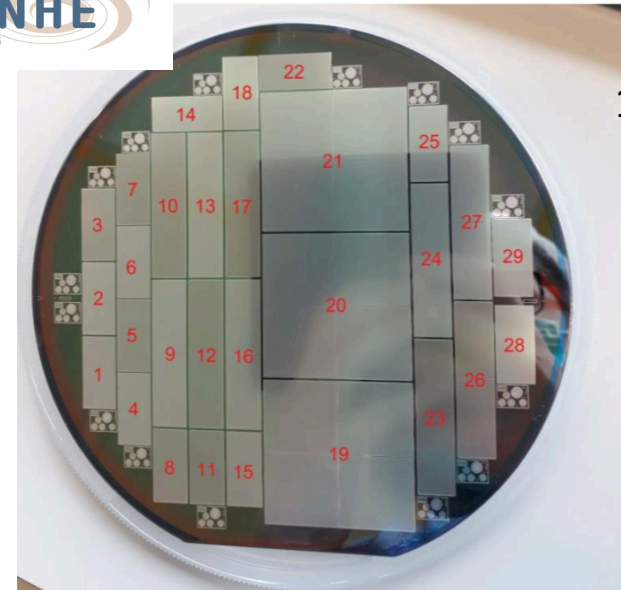


6" **130 μm thick** n-on-p
 INFN ATLAS/CMS project
 Active Edge technology
 Pixel-to-edge down to 50 μm
 RD53a compatible sensors
 Measured on beam,
 after irradiation too

JINST 14 (2019) no. 07, C07001



P4

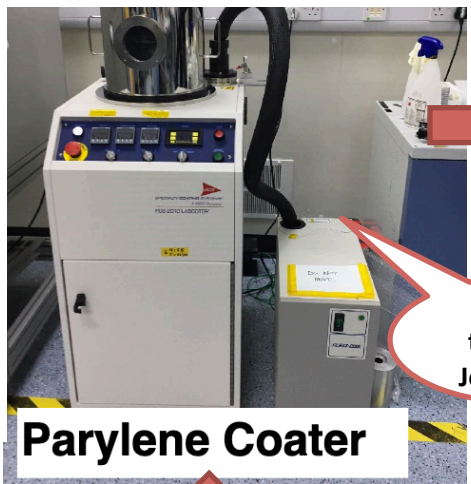
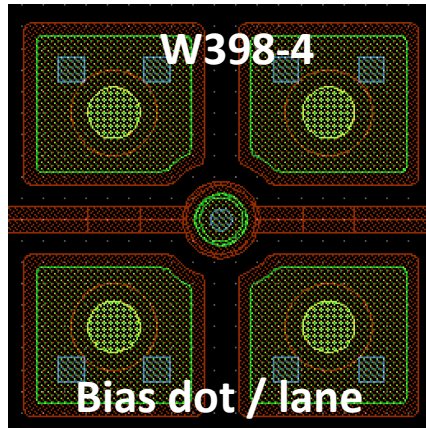
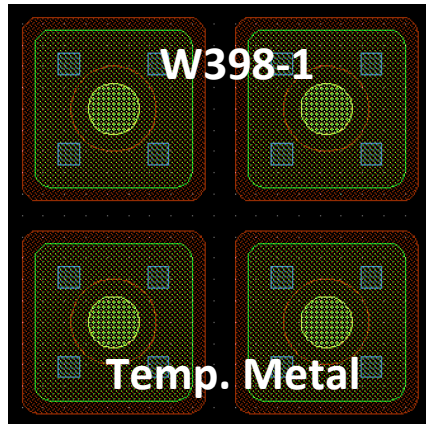


16 singles
 10 doubles
 3 quads

6" **50 μm thick**, ~ k Ω /cm p-type
 sensor wafer with 500 μm support
 wafer (SOI)
 Single, double and quad RD53a
 compatible chip sensors
 Split on: biasing structure and
 guard ring (GR) design
 Measured on beam

PAE3, 130 μM THICK MODULES: RESULTS

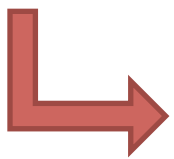
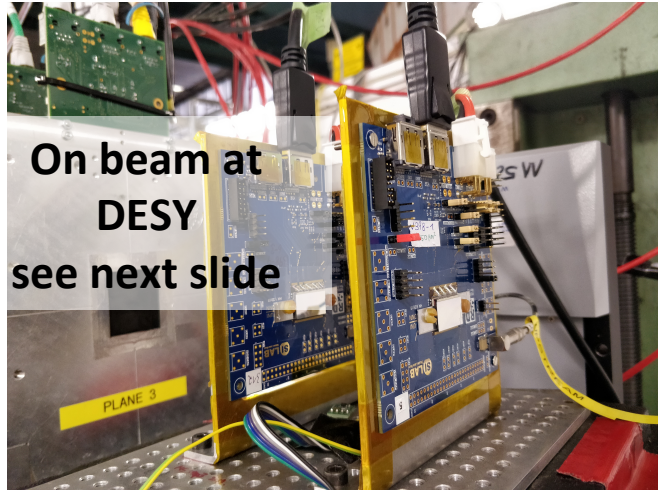
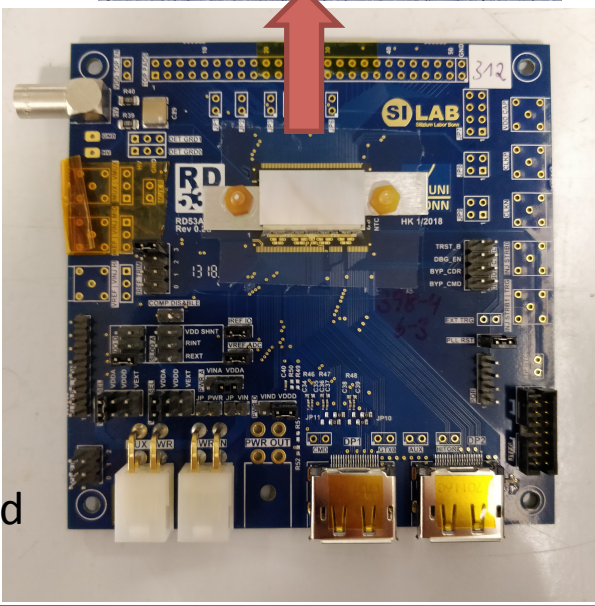
2 modules assembled



Irr. w/ 27 MeV protons @ Birmingham, $\Phi=1.7 \times 10^{15}$ (plans to re-irr.)

Many thanks to Jon Taylor!

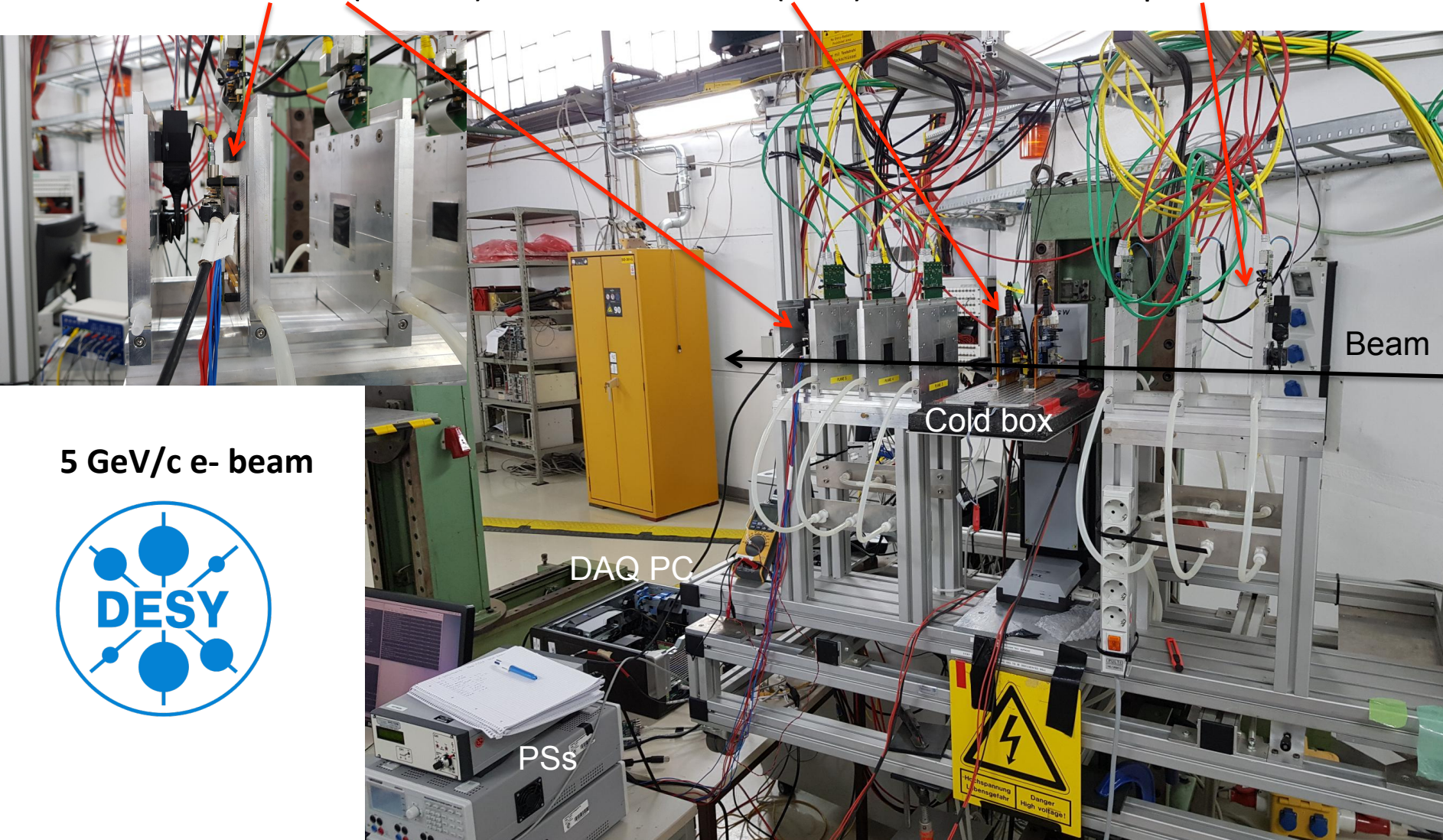
Many thanks to Amelia Hunter and Laura Gonella!



(W398-4 to be reworked as unresponsive)

Testbeam setup

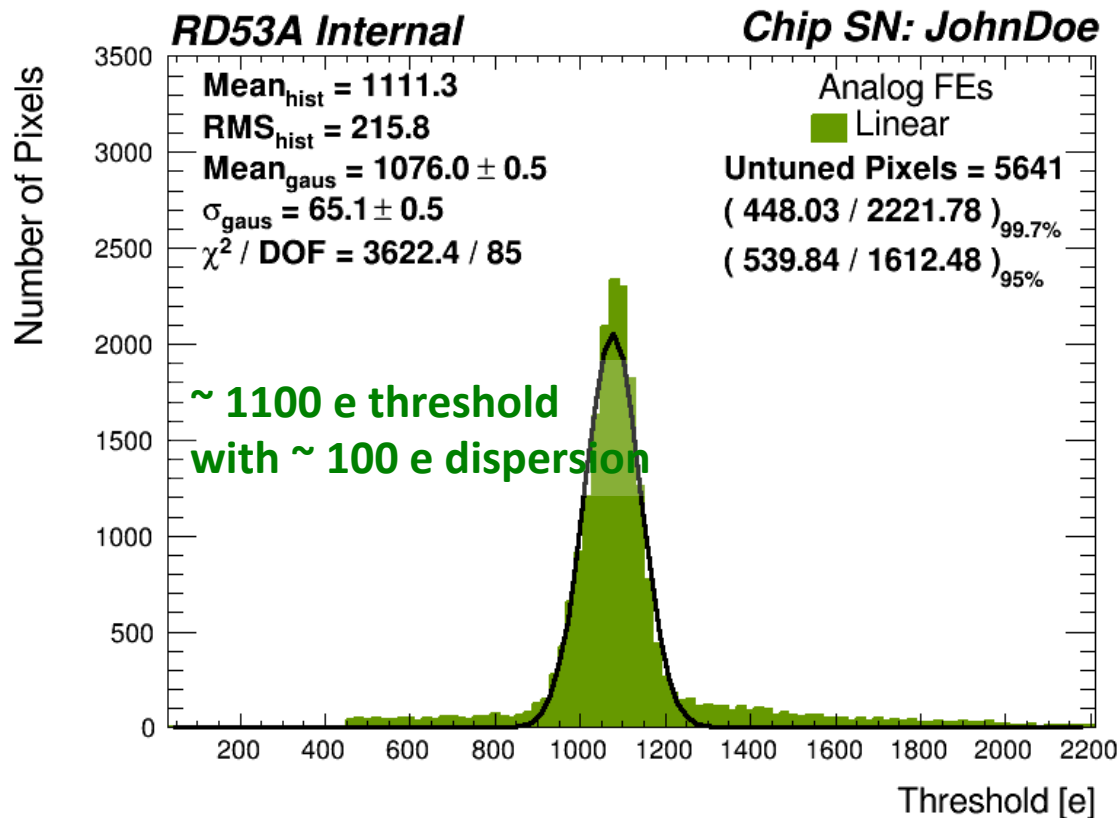
1 FEI4 reference (MMC3) + 2 RD53A DUTs (Yarr) + EUDET telescope



5 GeV/c e- beam



Threshold tuning

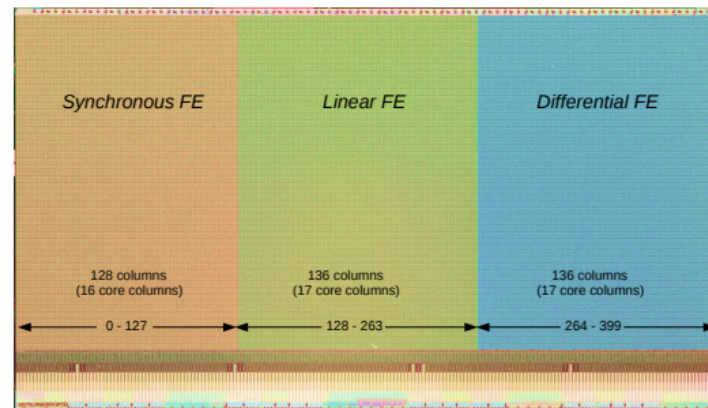
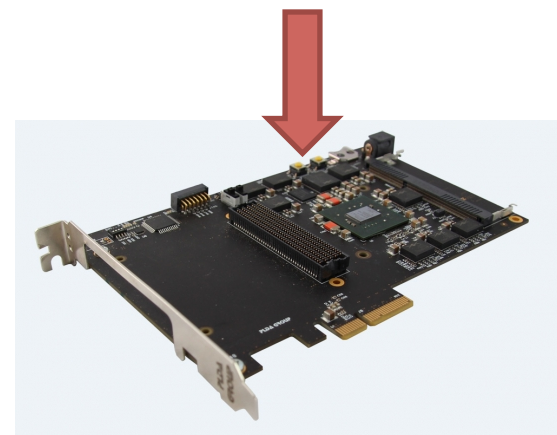


RD53a chip: prototype roc for ATLAS ITk pixels
400 cols x 192 rows, 50 μm x 50 μm pitch
Three analog FE flavours implemented
Here we show results only for the Linear FE

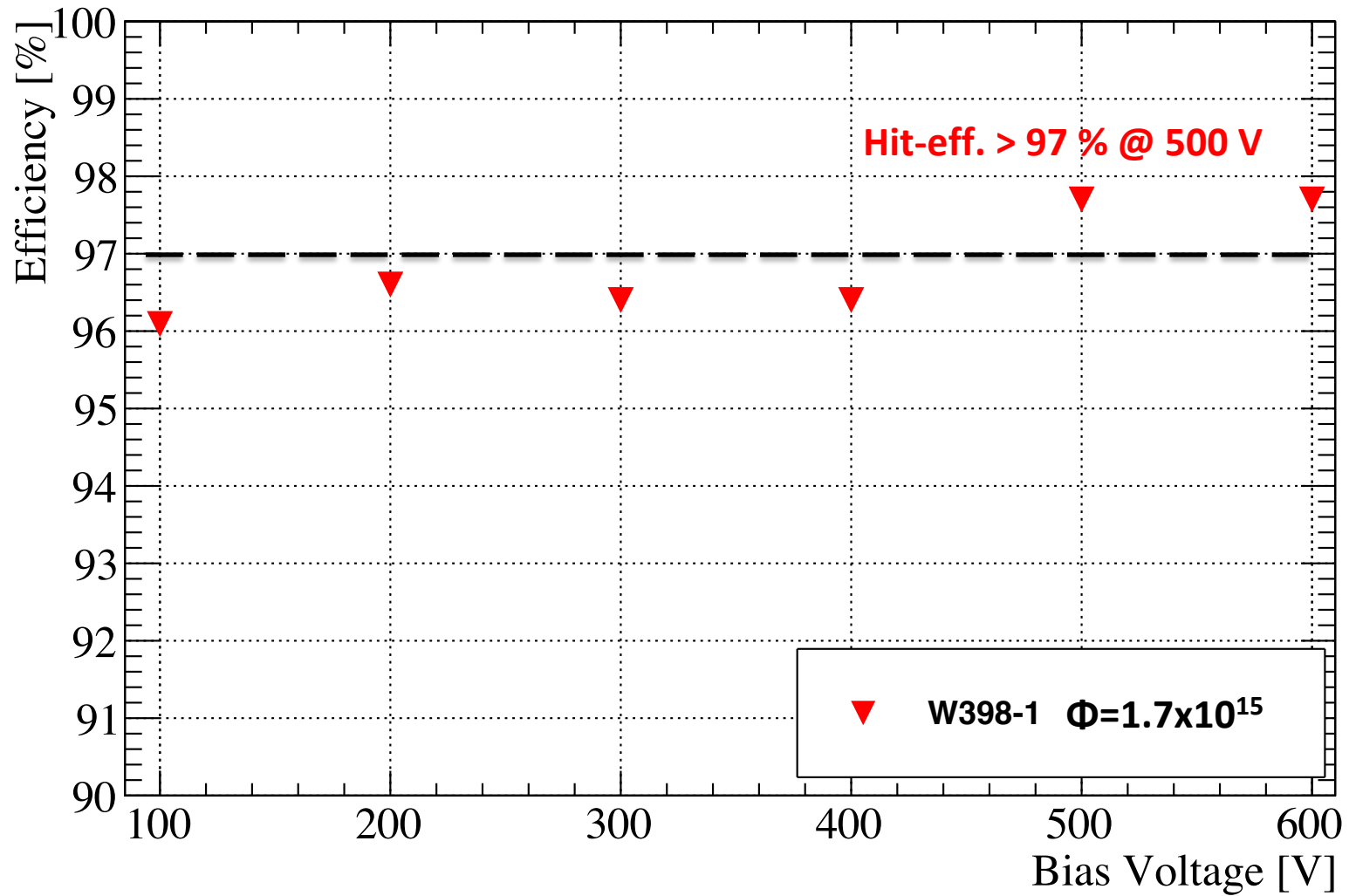


Results obtained using YARR DAQ system

T. Heim 2017
J. Phys.: Conf. Ser.898 032053
<https://yarr.readthedocs.io/>



Hit-efficiency

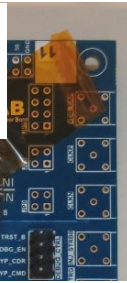


P4, 50 μM THICK MODULES: RESULTS

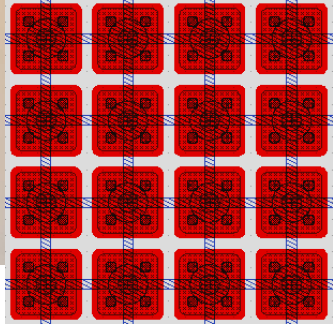
5 modules assembled on Single Chip Card

All $50 \times 50 \mu\text{m}^2$, bump-bonded at Leonardo, wirebonded at CERN

Temp. Metal
250 μm wide edge



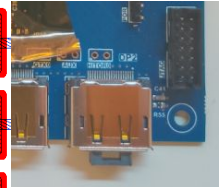
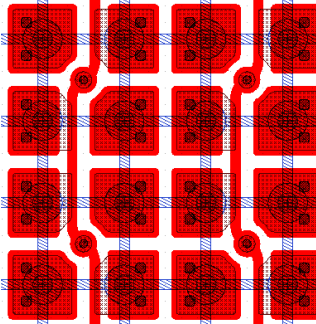
TM, GR250



PT w/ wavy bias lane
250 μm wide edge



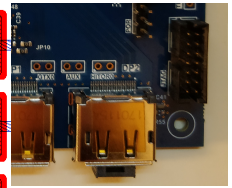
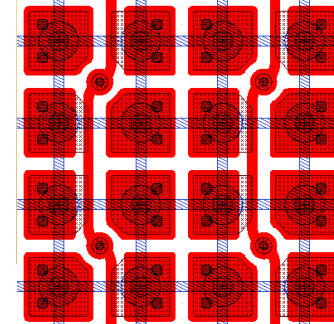
PT-W, GR250



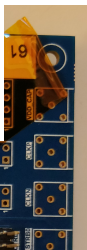
PT w/ wavy bias lane
450 μm wide edge



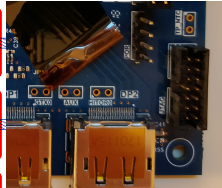
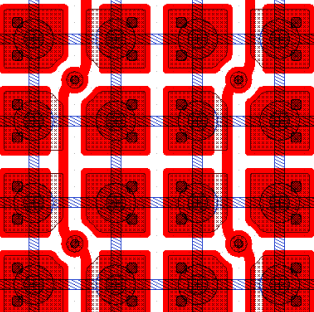
PT-W, GR450



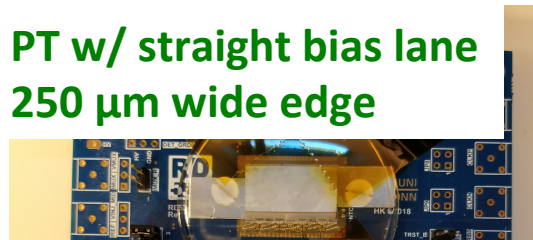
PT w/ wavy bias lane
450 μm wide edge



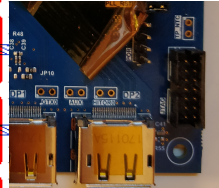
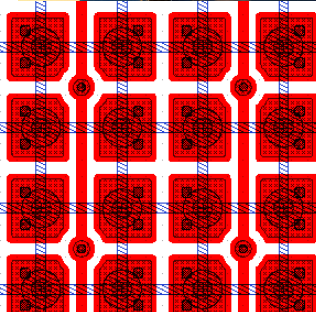
PT-W, GR450



PT w/ straight bias lane
250 μm wide edge



PT-S, GR250

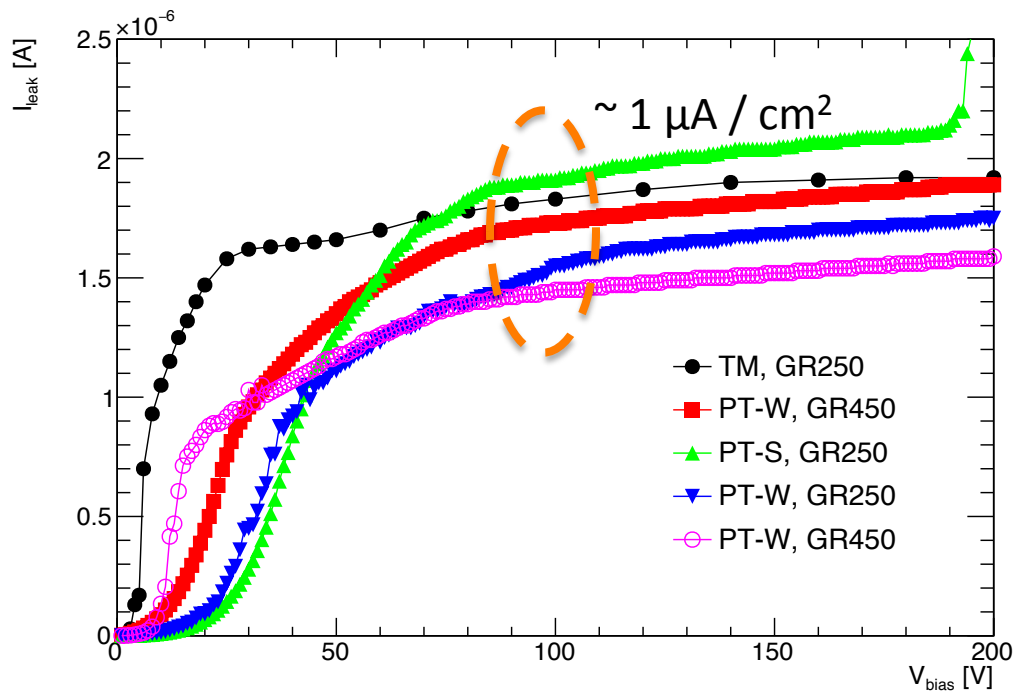


Unfortunately roc
unresponsive so no
data for this design

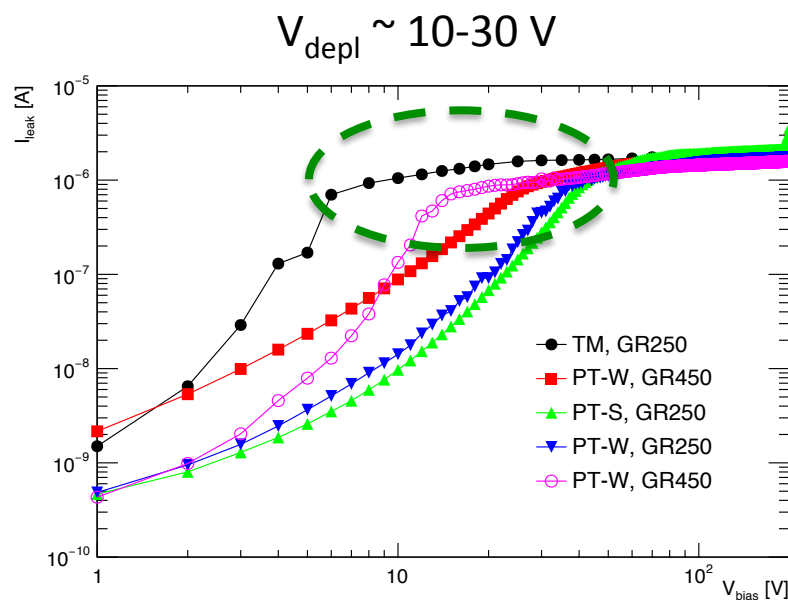


IV curves

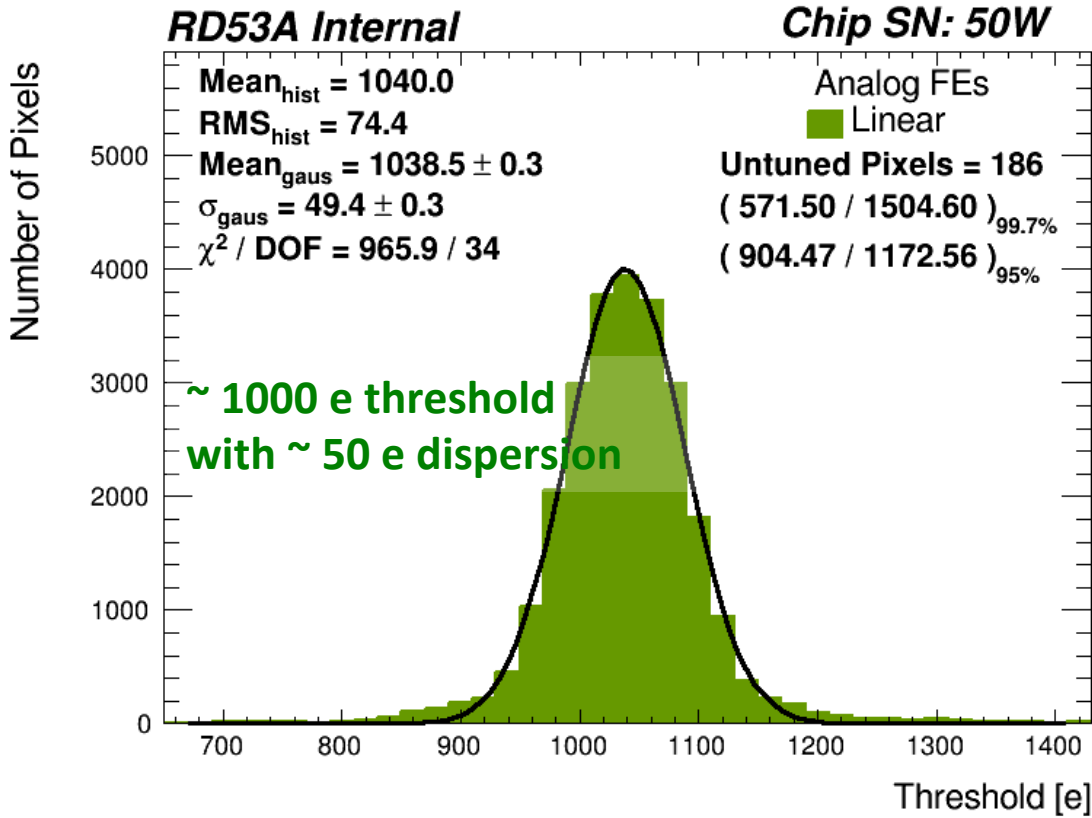
Modules mounted on SCC, roc configured, in climate chamber at 20 C



$V_{\text{BD}} > \sim 200 \text{ V}$

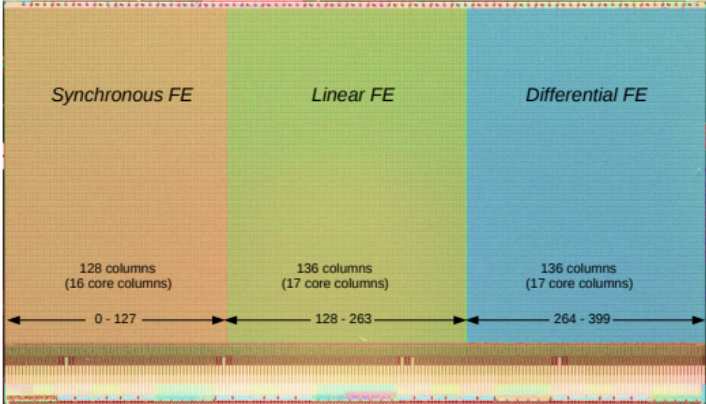


Threshold tuning

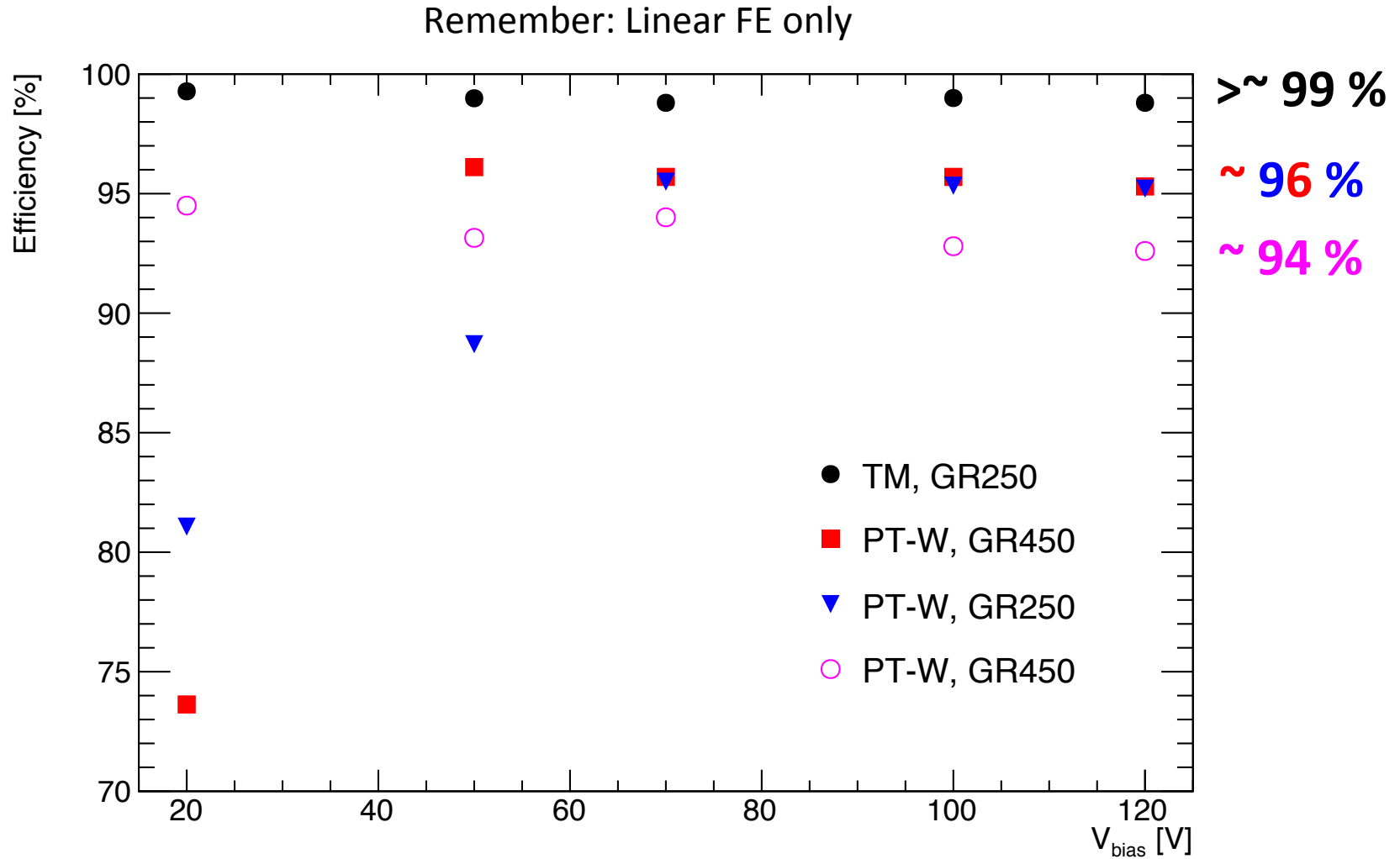


Results obtained using YARR
DAQ system

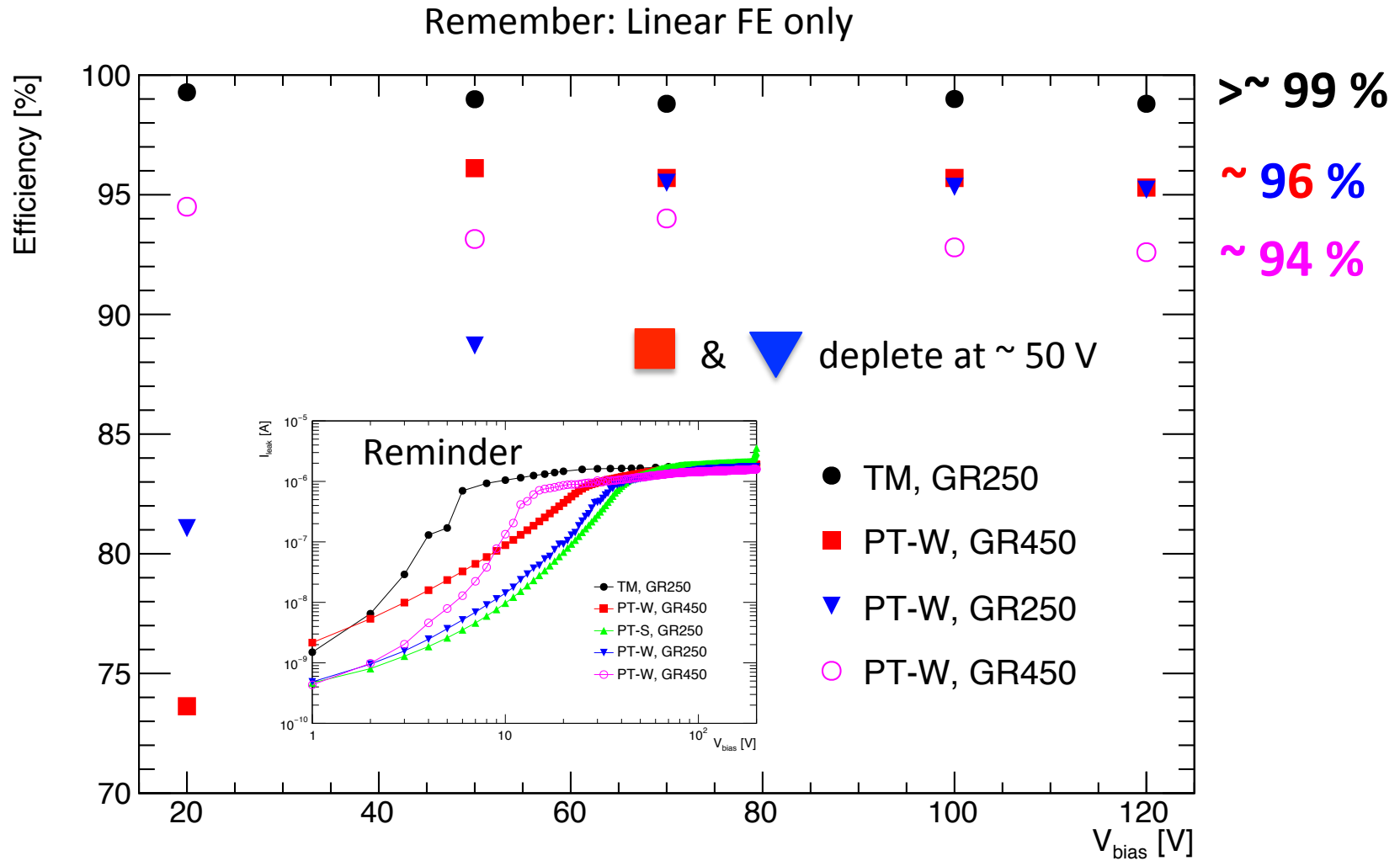
We show results only for the Linear FE



Hit-efficiency



Hit-efficiency

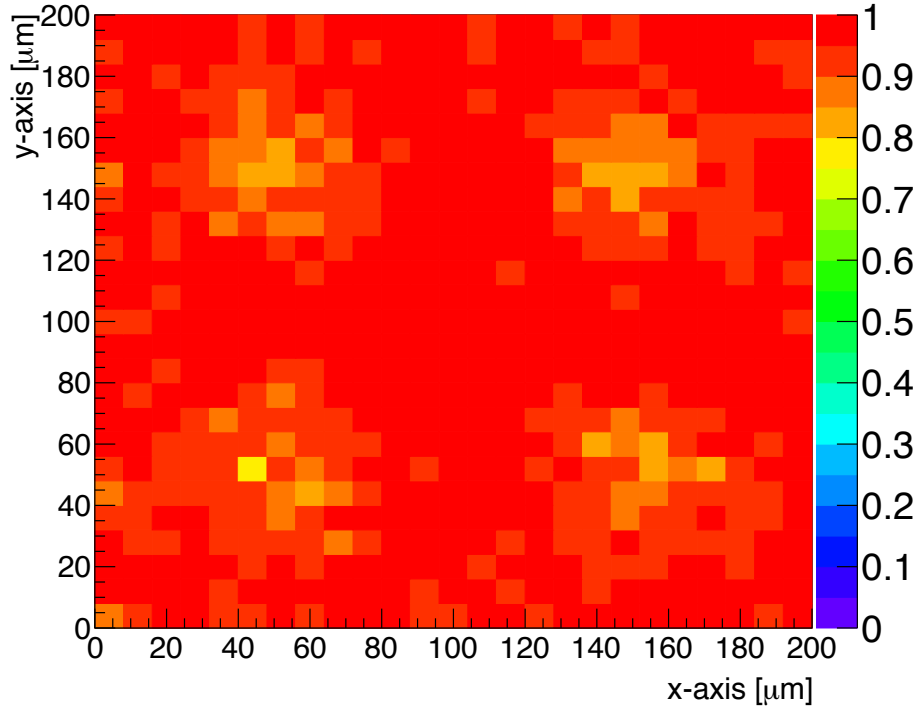


In-pixel efficiency

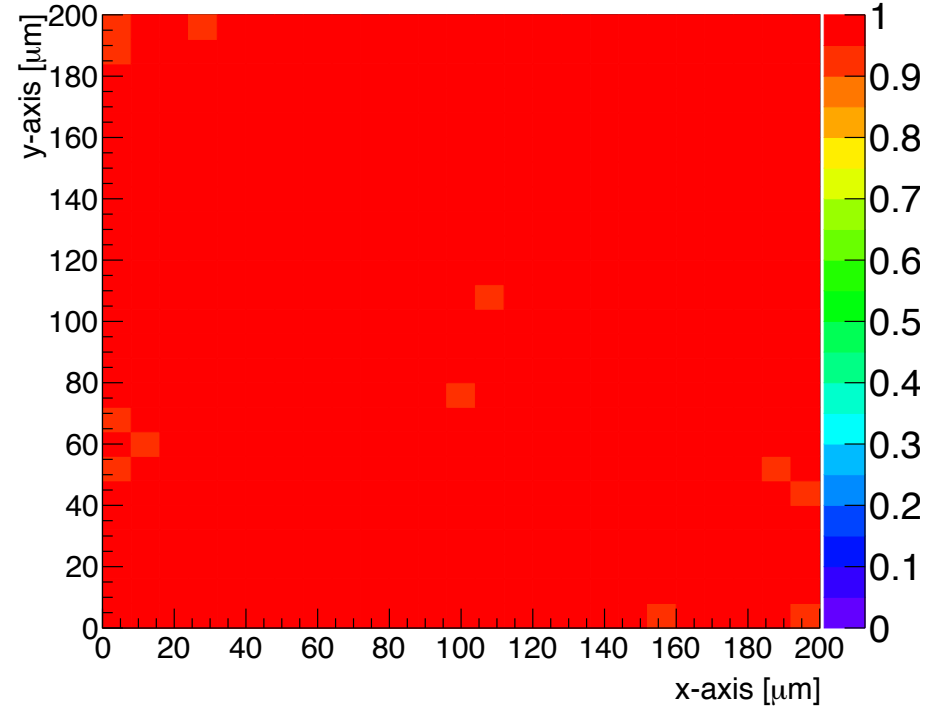
Remember: Linear FE only

N.B. tracks at normal incidence

Hit-eff. folded in a 4x4 pixel map



PT-W, GR250



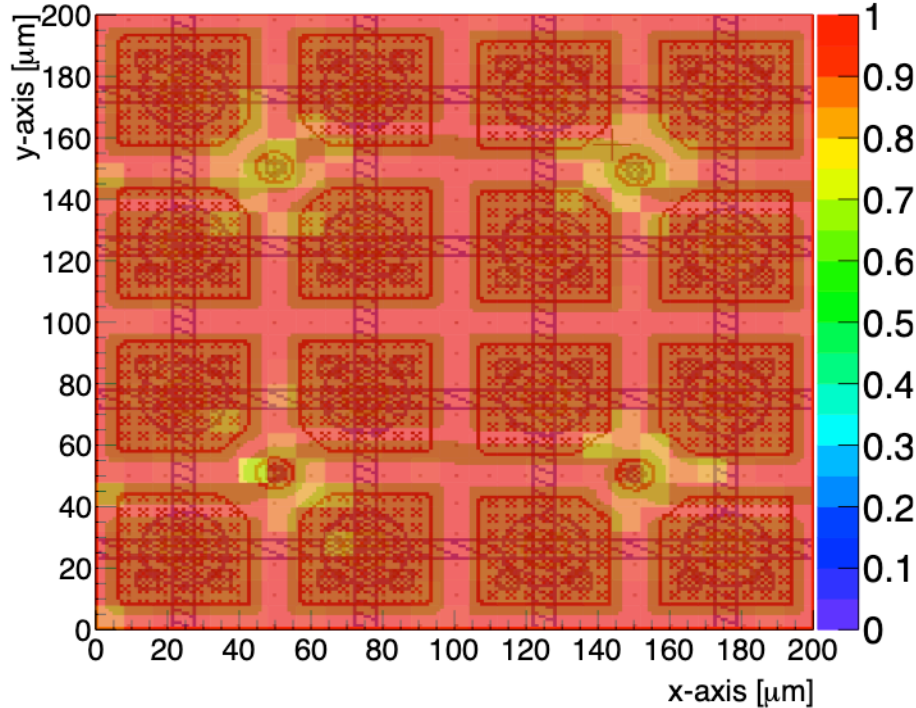
TM, GR250

In-pixel efficiency

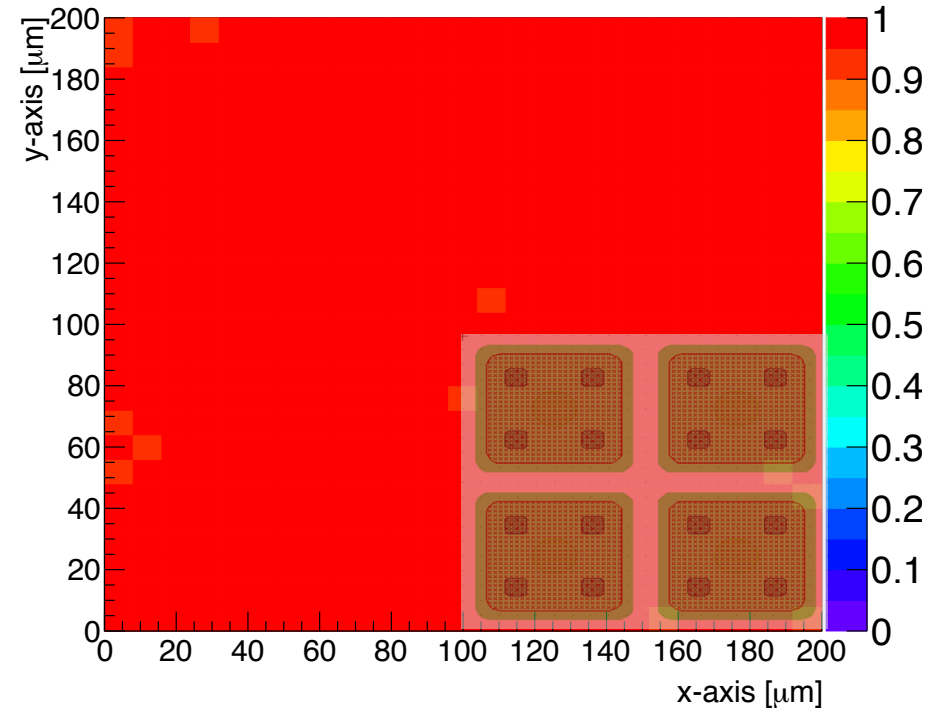
Remember: Linear FE only

N.B. tracks at normal incidence

Hit-eff. folded in a 4x4 pixel map



PT-W, GR250



TM, GR250

About 3-4% hit-eff. loss in bias dot region

Module w/o permanent biasing structure shows uniform eff.

Conclusions and Outlook

- New hadronic colliders impose light and high efficient silicon sensors for tracking in unprecedented harsh environments
- Thin n-on-p pixels are promising candidates
- Small pitches are becoming available
- LPNHE and FBK produced thin (130 μm) sensors which proved to be radiation hard for HL-LHC
- Very thin sensors (50 μm) show promising results before irradiation and two of them will be tested in DESY in ~ 1 month after irradiation to $5 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$

Acknowledgments

- PAE3 planar pixel production presented in this paper are supported by the Italian National Institute for Nuclear Research (INFN), Projects ATLAS, CMS, RD-FASE2 (CSN1)
- Many thanks to Laura and Amelia for taking care of irradiations
- Many thanks to Jon for parylene coating deposition on our modules
- Authors received support for irradiation and testbeam campaigns via the H2020 project AIDA-2020, GA no. 654168
- Some of the measurements leading to these results have been performed at the Test Beam Facility at DESY Hamburg (Germany), a member of the Helmholtz Association (HGF)
- Many thanks to the ATLAS ITk Pixels testbeam community



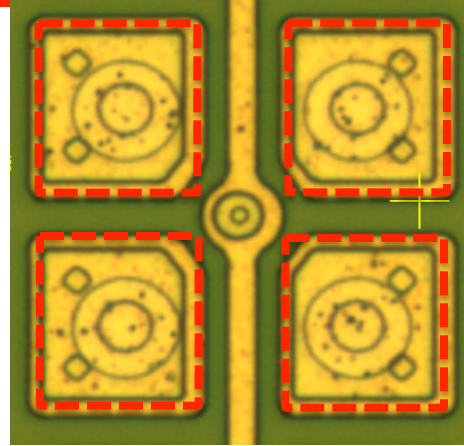
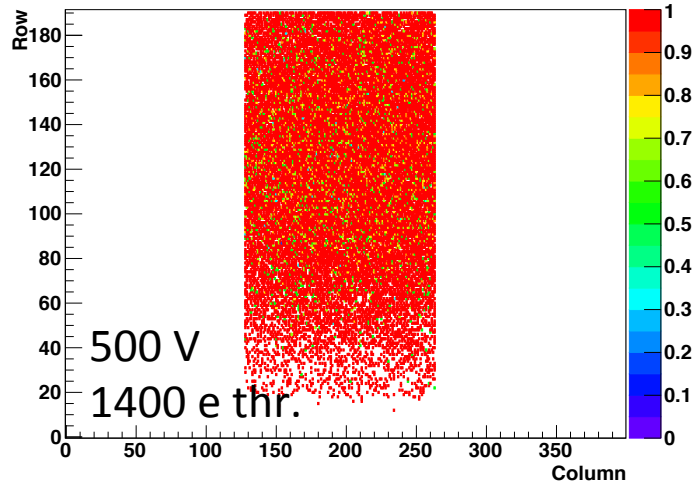


THANK YOU FOR YOUR ATTENTION!

Backup

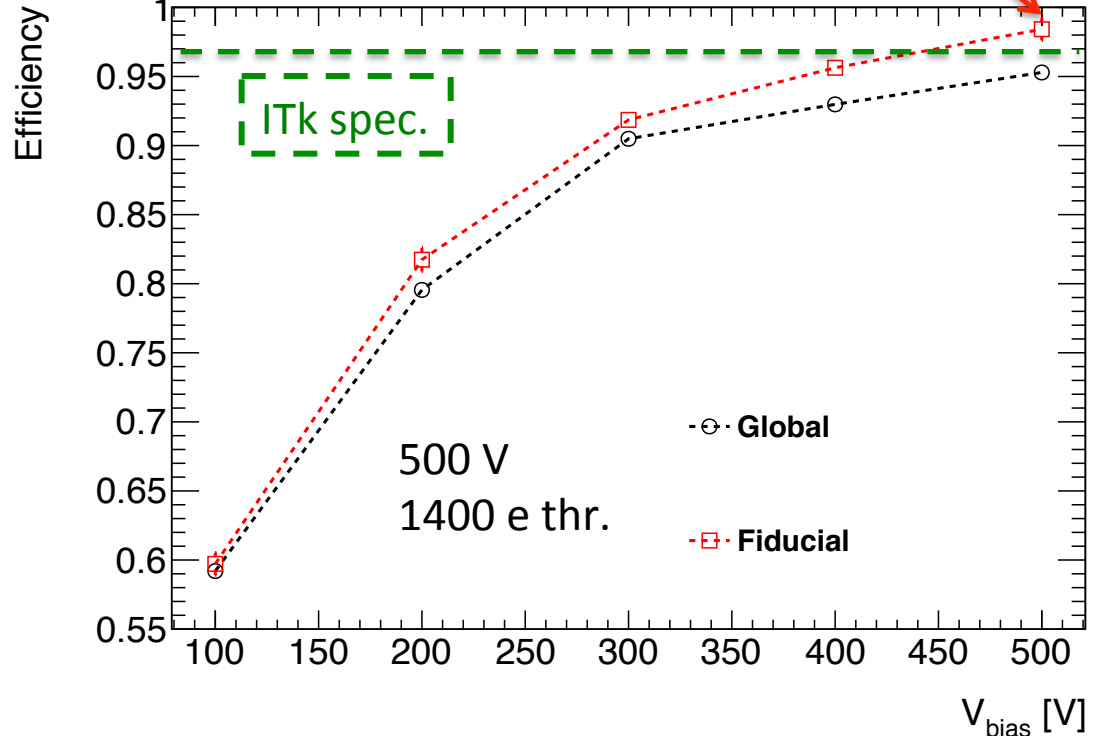
PAE3 - Performance of irradiated RD53A

Irr. at CERN IRRAD @ $\langle \Phi \rangle = 3.5 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$



Inner (fiducial) region

98.4% @ 500 V

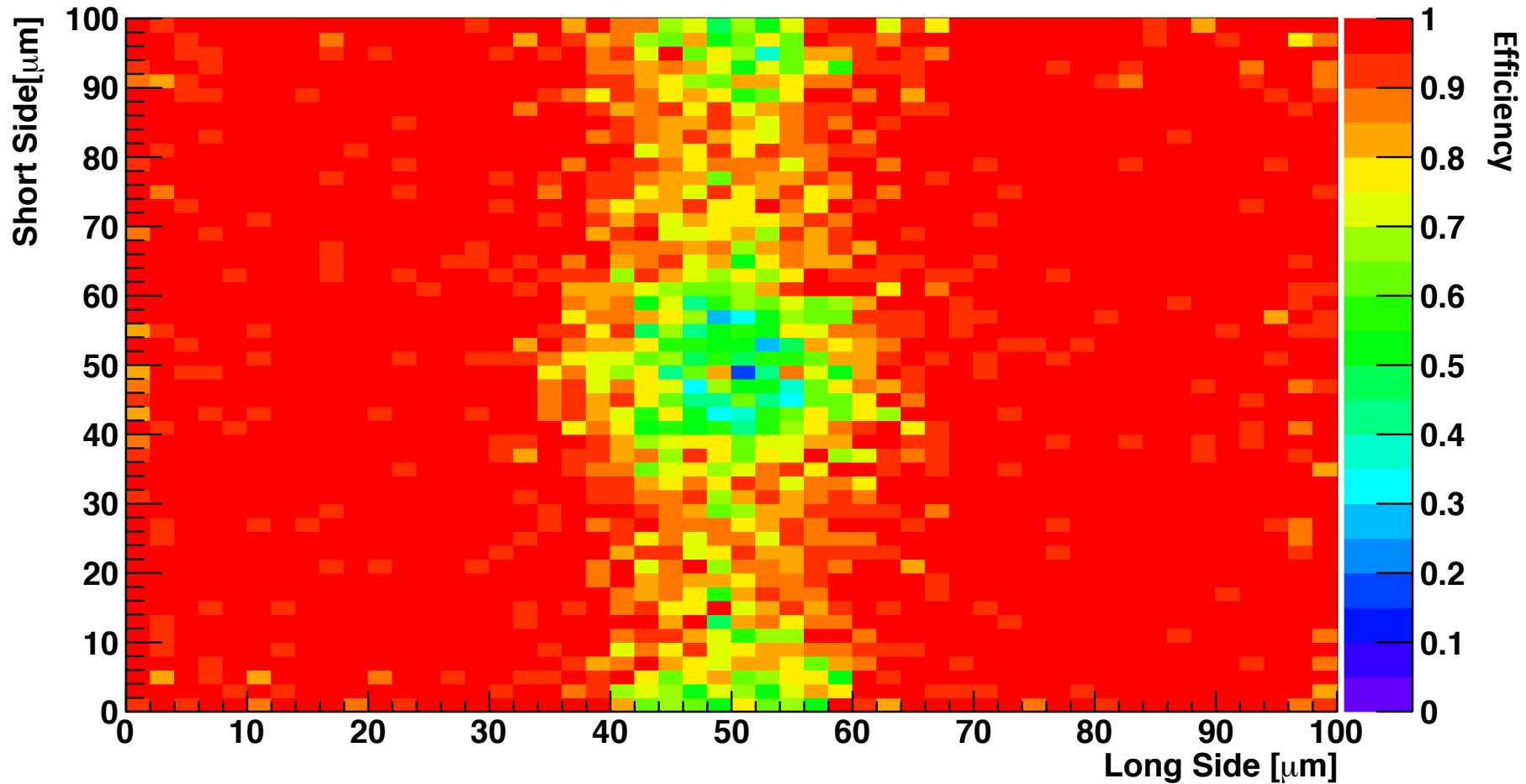


Significant efficiency loss when whole matrix is considered

Restricting analysis to the inner part of the cell brings back > 97% hit efficiency

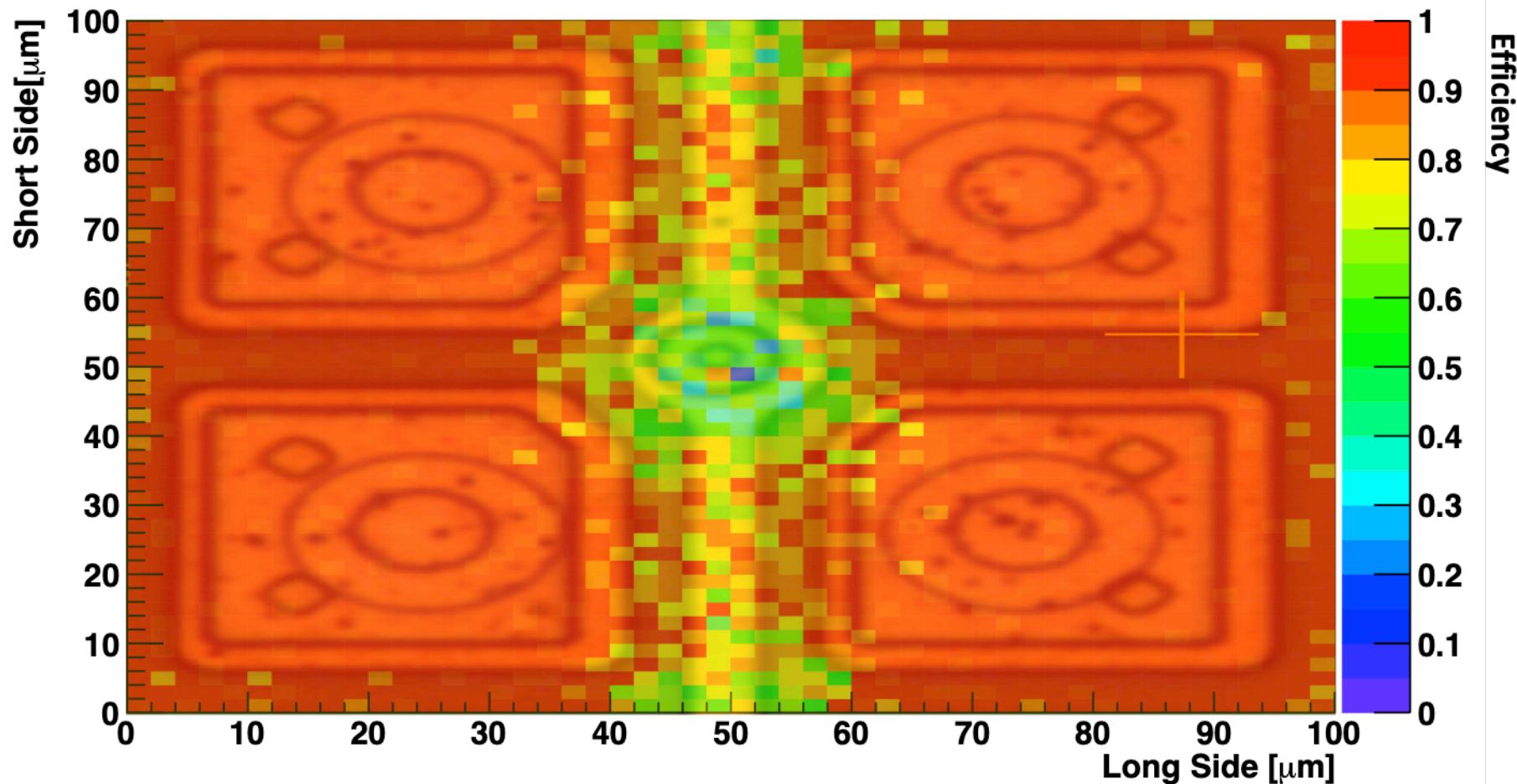
PAE3 - Hit efficiency map

500 V
1400 e thr. $\langle \Phi \rangle = 3.5 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$



PAE3 - Hit efficiency map

500 V
1400 e thr. $\langle\Phi\rangle = 3.5 \times 10^{15} \text{ n}_{\text{eq}}/\text{cm}^2$



New thin n-on-p wafer map

